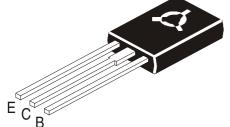


# BD175BD176BD177BD178BD179BD180NPNPNP

TO126 Plastic Package

## EPITAXIAL SILICON POWER TRANSISTORS



### Intended for use in Medium Power Linear Switching Applications

#### ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BD175 BD176	BD177 BD178	BD179 BD180	UNIT
Collector -Emitter Voltage	V <sub>CEO</sub>	45	60	80	V
Collector -Base Voltage	V <sub>CBO</sub>	45	60	80	V
Emitter Base Voltage	V <sub>EBO</sub>		5.0		V
Collector Current	I <sub>C</sub>		3.0		Α
Collector Peak Current	I <sub>CM</sub>	7.0			Α
Power Dissipation @ T <sub>a</sub> =25 <sup>o</sup> C	P <sub>D</sub>		1.25		W
Derate above 25ºC			10		mW/ºC
Power Dissipation @ T <sub>c</sub> =25 <sup>e</sup> C	PD		30		W
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>		- 65 to +150		°C

#### THERMAL CHARACTERISTICS

Junction to Ambient in free air	R <sub>th (j-a)</sub>	100	ºC/W
Junction to Case	R <sub>th (j-c)</sub>	4.16	ºC/W

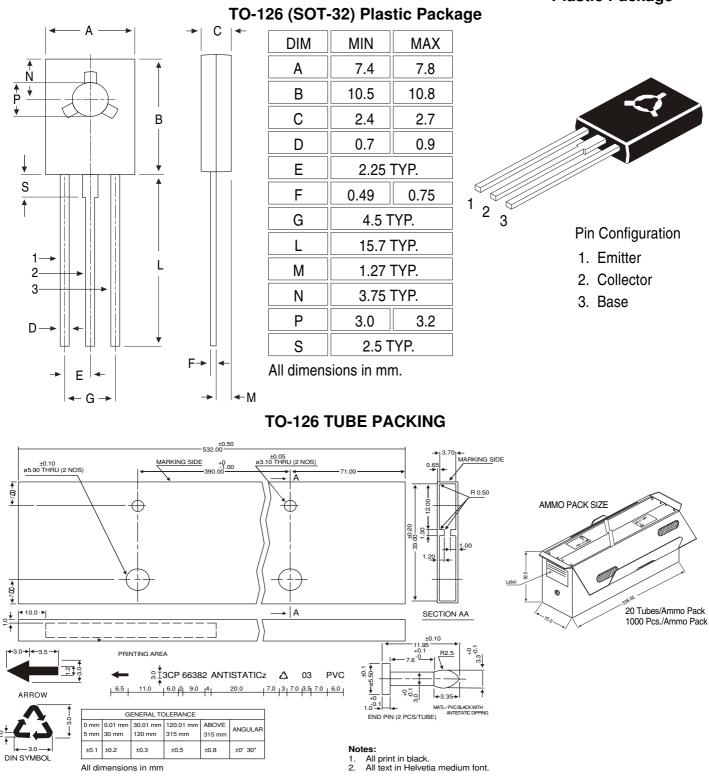
#### ELECTRICAL CHARACTERISTICS (Tc=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION		MIN	MAX	UNIT
Collector Cut off Current	I <sub>CBO</sub>	V <sub>CB</sub> =45V, I <sub>E</sub> =0	BD175/76		100	μA
		V <sub>CB</sub> =60V, I <sub>E</sub> =0	BD177/78		100	μA
		V <sub>CB</sub> =80V, I <sub>E</sub> =0	BD179/80		100	μA
Emitter Cut off Current	I <sub>EBO</sub>	$V_{EB}=5V, I_{C}=0$			1.0	mA
Collector Emitter Sustaining Voltage	*V <sub>CEO (sus)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =0	BD175/76	45		V
			BD177/78	60		V
			BD179/80	80		V
Collector Emitter Saturation Voltage	*V <sub>CE (sat)</sub>	I <sub>C</sub> =1A, I <sub>B</sub> =0.1A			0.8	V
Base Emitter on Voltage	*V <sub>BE (on)</sub>	$I_{C}=1A, V_{CE}=2V$			1.3	V
DC Current Gain	*h <sub>FE</sub>	I <sub>C</sub> =150mA, V <sub>CE</sub> =2V		40		
		$I_{C}=1A, V_{CE}=2V$		15		
	*h <sub>FE</sub> Group	I <sub>C</sub> =150mA, V <sub>CE</sub> =2V	- 6	40	100	
			- 10	63	160	
		Only BD175/76/79	- 16	100	250	
Transition Frequency	f⊤	I <sub>C</sub> =250mA, V <sub>CE</sub> =10V		3.0		MHz

\*Pulse test:- Pulse width=300 $\mu s,$  Duty cycle=1.5%

BD175	BD176
BD177	BD178
BD179	BD180
NPN	PNP

TO126 Plastic Package



#### **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

BD175	BD176
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#### Disclaimer

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